TOSHIBA JDP2S02T

TOSHIBA DIODE SILICON EPITAXIAL PIN TYPE

J D P 2 S 0 2 T

UHF~VHF BAND RF ATTENUATOR APPLICATIONS

Suitable for reducing set's size as a result from enabling highdensity mounting due to 2-pin small packages.

Low Series Resistance: $r_S = 1.0 \Omega$ (Typ.)

: $C_T = 0.3 pF (Typ.)$ Low Capacitance

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage	$v_{ m R}$	30	V
Foward Current	${ m I_F}$	50	mA
Junction Temperature	$T_{ m j}$	125	°C
Storage Temperature Range	$\mathrm{T}_{\mathrm{stg}}$	-55~125	°C

±0.05 CATHODE MARK **TESC JEDEC EIAJ TOSHIBA** 1-1H1A

Unit in mm

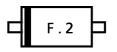
Weight: 0.0013 g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Reverse Voltage	v_{R}	$I_R = 10 \mu A$	30	_	_	V
Reverse Current	I_{R}	$V_R = 30 V$	_	_	0.1	μ A
Forward Voltage	$ m V_{ m F}$	$I_{ m F}=50{ m mA}$	_	0.9	0.95	V
Capacitance	C_{T}	$V_R = 1 V, f = 1 MHz$	_	0.3	0.5	pF
Series Resistance	r _S	$I_{\rm F} = 10 {\rm mA, \ f} = 100 {\rm MHz}$	_	1.0	1.5	Ω

Signal level when capacitance is measured: $Vsig = 20 \, mV_{rms}$

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